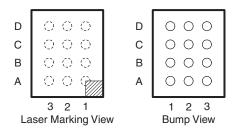
0.7-Ω DUAL SPDT ANALOG SWITCH WITH NEGATIVE RAIL CAPABILITY AND 1.8-V COMPATIBLE INPUT LOGIC

Check for Samples: TS5A22366

FFATURES

- Negative Signaling Capability: Maximum Swing From –2.75 V to 2.75 V (V₊ = 2.75 V)
- Low ON-State Resistance (0.7 Ω Typ)
- Excellent ON-State Resistance Matching
- 1.8-V Compatible Control Input Threshold Independent of V₊
- Control Inputs Are 5.5-V Tolerant
- 2.25-V to 5.5-V Power Supply (V₁)
- · Low Charge Injection
- Specified Break-Before-Make Switching
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

YFC PACKAGE



- ESD Performance Tested Per JESD 22
 - 2500-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
 - 200-V Machine Model (A115-A)

APPLICATIONS

- Cell Phones
- PDAs
- Portable Instrumentation
- Audio Routing
- Portable Media Players

YFC PACKAGE TERMINAL ASSIGNMENTS

| D | NC1 | V ₊ | NC2 |
|---|------|---------------------|------|
| С | COM1 | GND | COM2 |
| В | NO1 | GND | NO2 |
| Α | IN1 | N.C. ⁽¹⁾ | IN2 |
| | 1 | 2 | 3 |

(1) N.C. -No internal connection

DESCRIPTION

The TS5A22366 is a dual single-pole double-throw (SPDT) analog switch that is designed to operate from 2.25 V to 5.5 V. The device features negative signal capability that allows signals below ground to pass through the switch without distortion.

The break-before-make feature prevents signal distortion during the transferring of a signal from one path to another. Low ON-state resistance, excellent channel-to-channel ON-state resistance matching, and minimal total harmonic distortion (THD) performance are ideal for audio applications.

The TS5A22366 is available is a ultra small 1.6 mm x 1.2 mm wafer-chip-scale package (WCSP) (0.4 mm pitch).

ORDERING INFORMATION

For package and ordering information, see the Package Option Addendum at the end of this document.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



Table 1. SUMMARY OF CHARACTERISTICS

 $V_{+} = 3.3 \text{ V}, T_{A} = 25^{\circ}\text{C}$

| Configuration | 2:1 Multiplexer/Demultiplexer (2 × SPDT) |
|--|--|
| Number of channels | 2 |
| ON-state resistance (ron) | 0.8 Ω |
| ON-state resistance match (Δr _{on}) | 0.08 Ω |
| ON-state resistance flatness (r _{ON(flat)}) | 0.3 Ω |
| Turn-on/turn-off time (t _{ON} /t _{OFF}) | 199 ns/182 ns |
| Break-before-make time (t _{BBM}) | 7.1 ns |
| Charge injection (Q _C) | 120 pC |
| Bandwidth (BW) | 32 MHz |
| OFF isolation (O _{ISO}) | –70 dB at 100 kHz |
| Crosstalk (X _{TALK}) | -70 dB at 100 kHz |
| Total harmonic distortion (THD) | 0.01% |
| Package option | 12-pin WCSP (YFC) |

Table 2. FUNCTION TABLE

| IN | NC TO COM, COM TO NC | NO TO COM, COM TO NO |
|----|-------------------------|-------------------------|
| L | ON | OFF |
| Н | OFF | ON |



APPLICATION BLOCK DIAGRAM

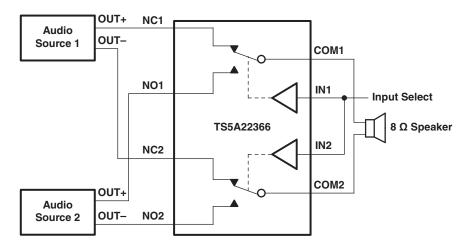


Figure 1. TS5A22366 Application Block Diagram

Negative Signaling Capacity

The TS5A22366 dual SPDT switch features negative signal capability that allows signals below ground to pass through without distortion. These analog switches operate from a single +2.3-V to +5.5-V supply. The input/output signal swing of the device is dependant of the supply voltage V_+ : the devices pass signals as high as V_+ and as low as $V_+ - 5.5$ V, including signals below ground with minimal distortion.

Table 3 shows the input/output signal swing the user can get with different supply voltages.

Table 3. Input/Output Signal Swing

| SUPPLY VOLTAGE, V+ | $\begin{aligned} & \text{MINIMUM} \\ & (V_{\text{NC}}, V_{\text{NO}}, V_{\text{COM}}) = V_{+} - 5.5 \end{aligned}$ | $\begin{array}{c} \text{MAXIMUM} \\ (\text{V}_{\text{NC}}, \text{V}_{\text{NO}}, \text{V}_{\text{COM}}) = \text{V}_{+} \end{array}$ |
|--------------------|--|---|
| 5.5 V | 0 V | 5.5 V |
| 4.2 V | −1.3 V | 4.2 V |
| 3.3 V | −2.2 V | 3.3 V |
| 3 V | –2.5 V | 3 V |
| 2.5 V | −3 V | 2.5 V |

Product Folder Links: TS5A22366



ABSOLUTE MINIMUM AND MAXIMUM RATINGS(1) (2)

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|-------------------------------------|---|---|--------------------|----------------------|------|
| V ₊ | Supply voltage range (3) | | -0.5 | 6 | V |
| $V_{NC} \ V_{NO} \ V_{COM}$ | Analog voltage range (3) (4) (5) | | V ₊ - 6 | V ₊ + 0.5 | V |
| I _K | Analog port diode current ⁽⁶⁾ | $V_+ < V_{NC}, V_{NO}, V_{COM} < 0$ | -50 | 50 | V |
| I _{NC} | ON-state switch current | $V_{+} < V_{NC}, V_{NO}, V_{COM} < 0$ $V_{NC}, V_{NO}, V_{COM} = 0 \text{ to } V_{+}$ | -150 | 150 | |
| I _{NO} I _{COM} | ON-state peak switch current ⁽⁷⁾ | | -300 | 300 | mA |
| VI | Digital input voltage range | | -0.5 | 6.5 | V |
| I _{IK} | Digital input clamp current (3) (4) | V _{IO} < V _I < 0 | -50 | | mA |
| I _{GND} I ₊ | Continuous current through V₊or GND | | -100 | 100 | mA |
| T _{stg} | Storage temperature range | Storage temperature range | | | °C |

⁽¹⁾ Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
- (3) All voltages are with respect to ground, unless otherwise specified.
- (4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (5) This value is limited to 5.5 V maximum.
- (6) Requires clamp diodes on analog port to V₊.
- 7) Pulse at 1-ms duration <10% duty cycle

THERMAL IMPEDANCE RATINGS

| | | | | UNIT |
|---------------|--|-------------|-------|------|
| θ_{JA} | Package thermal impedance ⁽¹⁾ | YFC package | 106.2 | °C/W |

(1) The package thermal impedance is calculated in accordance with JESD 51-7.

ELECTRICAL CHARACTERISTICS FOR 2.5-V SUPPLY⁽¹⁾

 $V_{+} = 2.25 \text{ V}$ to 2.7 V, $T_{\Delta} = -40 ^{\circ}\text{C}$ to 85 $^{\circ}\text{C}$ (unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONI | DITIONS | T _A | V ₊ | MIN | TYP | MAX | UNIT |
|---------------------------------------|--|--|------------------------------|----------------|----------------|----------------------|------|----------------|------|
| Analog Switch | | | | | | | | | |
| Analog signal range | V_{COM} , V_{NO} , V_{NC} | | | | | V ₊ - 5.5 | | V ₊ | Ω |
| ON-state resistance | r _{on} | V_{NC} or $V_{NO} = V_{+}$, 1.5 V, $V_{+} - 5.5$ V $I_{COM} = -100$ mA, | Switch ON, See Figure 15 | 25°C Full | 2.25 V | | 1 | 1.8 | Ω |
| ON-state resistance match between | Δr _{on} | V_{NC} or $V_{NO} = 1.5 \text{ V}$, $I_{COM} = -100 \text{ mA}$, | Switch ON, See Figure 15 | 25°C Full | 2.25 V | | 0.05 | 1 | Ω |
| channels ON-state resistance flatness | r _{on(flat)} | V_{NC} or $V_{NO} = V_{+}$, 1.5 V, $V_{+} - 5.5$ V $I_{COM} = -100$ mA, | Switch ON, See Figure 16 | 25°C Full | 2.25 V | | 0.53 | 1.5 1.6 | Ω |
| NC, NO OFF leakage current | I _{NC(OFF)} , I _{NO(OFF)} | $\begin{split} &V_{NC} = 2.25, V_+ - 5.5 V \\ &V_{COM} = V_+ - 5.5 V, \\ &2.25, \\ &V_{NO} = Open, \\ ∨ \\ &V_{NO} = 2.25, V_+ - 5.5 V \\ &V_{COM} = V_+ - 5.5 V, \\ &2.25, \end{split}$ | Switch OFF, See Figure 16 | 25°C | 2.7 V | -50 -375 | | 375 | nA |
| COM ON leakage current | I _{COM(ON)} | $\begin{split} &V_{NC} = Open, \\ &V_{NC} \text{ and } V_{NO} = Open, \\ &V_{COM} = V_+, V_+ - 5.5 \text{ V}, \end{split}$ | See Figure 17 | 25°C Full | 2.7 V | -50 -375 | | 50 375 | nA |
| Digital Control In | puts (IN, EN) | 2) | | | | • | | | |
| Input logic high | V _{IH} | | | Full | | 1.05 | | 5.5 | V |
| Input logic low | V _{IL} | | | Full | | | | 0.65 | V |
| Input leakage current | I _{IH} , I _{IL} | V _{IN} = 1.8 V or GND | | 25°C Full | 2.7 V | -700 -700 | | 700 700 | nA |

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

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⁽²⁾ All unused digital inputs of the device must be held at V₊ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



ELECTRICAL CHARACTERISTICS FOR 2.5-V SUPPLY⁽¹⁾ (continued)

 $V_{+} = 2.25 \text{ V}$ to 2.7 V, $T_{A} = -40 ^{\circ}\text{C}$ to 85 $^{\circ}\text{C}$ (unless otherwise noted)

| PARAMETER | SYMBOL | TEST CON | DITIONS | TA | V ₊ | MIN | TYP | MAX | UNIT |
|----------------------------|--|---|--|------|--------------------|-----|------|-----|------|
| Dynamic | • | | | | · I | | | | |
| | | V V | C 25 pF | 25°C | 2.5 V | | 193 | 297 | |
| Turn-on time | t _{ON} | $V_{COM} = V_+,$ $R_L = 300 \Omega,$ | C _L = 35 pF, See Figure 19 | Full | 2.25 V to 2.7 V | | | 350 | ns |
| | | V V | C 25 pF | 25°C | 2.5 V | | | 266 | |
| Turn-off time | t _{OFF} | $V_{COM} = V_+,$ $R_L = 300 \Omega,$ | C _L = 35 pF, See Figure 19 | Full | 2.25 V to 2.7 V | | | 320 | ns |
| Break-before- make time | t _{BBM} | $V_{NC} = V_{NO} = V_{+}/2$ $R_{L} = 300 \Omega,$ | C _L = 35 pF, See Figure 20 | 25°C | 2.5 V | 1 | 15.6 | | ns |
| Charge injection | $Q_{\mathbb{C}}$ | $V_{GEN} = 0,$ $R_{GEN} = 0,$ | $C_L = 1 \text{ nF},$ See Figure 24 | 25°C | 2.5 V | | 91 | | рC |
| NC, NO OFF capacitance | C _{NC(OFF)} , C _{NO(OFF)} | V_{NC} or $V_{NO} = V_{+}$ or GND, Switch OFF, | See Figure 18 | 25°C | 2.5 V | | 51 | | pF |
| NC, NO ON capacitance | C _{NC(ON)} , C _{NO(ON)} | V_{NC} or $V_{NO} = V_{+}$ or GND, Switch OFF, | See Figure 18 | 25°C | 2.5 V | | 181 | | pF |
| COM ON capacitance | C _{COM(ON)} | $V_{COM} = V_{+}$ or GND, Switch ON, | See Figure 18 | 25°C | 2.5 V | | 181 | | pF |
| Digital input capacitance | C _I | $V_I = V_+ \text{ or GND}$ | See Figure 18 | 25°C | 2.5 V | | 3 | | pF |
| Bandwidth | BW | $R_L = 50 \Omega$, | Switch ON, See Figure 20 | 25°C | 2.5 V | | 32 | | MHz |
| | | $R_1 = 50 \Omega$, Switch | f = 100 kHz, | | | | -70 | | |
| OFF isolation | O _{ISO} | OFF, | f = 1 MHz, | 25°C | 2.5 V | | -50 | | dB |
| | | See Figure 22 | f = 5 MHz, | | | | -35 | | |
| | | P = 50 O Switch ON | f = 100 kHz, | | | | -70 | | |
| Crosstalk | X _{TALK} | $R_L = 50 \Omega$, Switch ON, See Figure 23 | f = 1 MHz, | 25°C | 2.5 V | | -50 | | dB |
| | | • | f = 5 MHz, | | | | -35 | | |
| Total harmonic distortion | THD | $R_{L} = 600 \Omega,$ $C_{L} = 50 \text{ pF},$ | f = 20 Hz to 20 kHz, See Figure 25 | 25°C | 2.5 V | | 0.02 | | % |
| Supply | | | | | | | | | |
| Positive supply current | I ₊ | V _I = 1.8 V or GND, | | Full | 2.7 V | | 6 | 12 | μΑ |

ELECTRICAL CHARACTERISTICS FOR 3.3-V SUPPLY⁽¹⁾

 $V_{+} = 3 \text{ V to } 3.6 \text{ V}, T_{A} = -40^{\circ}\text{C} \text{ to } 85^{\circ}\text{C} \text{ (unless otherwise noted)}$

| PARAMETER | SYMBOL | TEST CON | DITIONS | TA | V ₊ | MIN | TYP | MAX | UNIT |
|---|-----------------------------------|--|------------------------------|--------------|----------------|----------------------|------|----------------|------|
| Analog Switch | | | | | | | | | |
| Analog signal range | V_{COM} , V_{NO} , V_{NC} | | | | | V ₊ - 5.5 | | V ₊ | Ω |
| | | V_{NC} or $V_{NO} \le V_+$, 1.5 | | 25°C | | | 0.8 | 1.3 | |
| ON-state resistance | r _{on} | $V_{+} - 5.5 V_{+}$ $I_{COM} = -100 \text{ mA},$ | Switch ON, See Figure 15 | Full | 3 V | | | 1.53 | Ω |
| ON-state | | | | 25°C | | | 0.08 | 0.17 | |
| resistance match between channels | Δr_{on} | V_{NC} or $V_{NO} = 1.5 \text{ V}$, $I_{COM} = -100 \text{ mA}$, | Switch ON, See Figure 15 | Full | 3 V | | | 0.3 | Ω |
| ON-state | | V_{NC} or $V_{NO} \le V_+$, 1.5 | | 25°C | | | 0.3 | 0.65 | |
| resistance flatness | r _{on(flat)} | $V_{+} = 5.5 V_{+}$ $I_{COM} = -100 \text{ mA},$ | Switch ON, See Figure 16 | Full | 3 V | 0.75 | Ω | | |
| | | $V_{NC} = 3, V_{+} - 5.5 V$ | | 25°C | | -50 | | 50 | |
| NC, NO OFF leakage current | INC(OFF), INO(OFF) | $\begin{split} &V_{COM} = V_+ - 5.5 \text{ V}, 3, \\ &V_{NO} = \text{Open}, \\ &\text{or} \\ &V_{NO} = 3 \text{ , } V_+ - 5.5 \text{ V} \\ &V_{COM} = V_+ - 5.5 \text{ V}, 3, \\ &V_{NC} = \text{Open}, \end{split}$ | Switch OFF, See Figure 16 | Full | 3.6 V | -375 | | 375 | nA |
| COM | | V_{NC} and V_{NO} = Open, | Switch ON | 25°C | | -50 | | 50 | |
| ON leakage current | I _{COM(ON)} | $V_{COM} = V_+, V_+ - 5.5 V,$ | | Full | 3.6 V | -375 | | 375 | nA |
| Digital Control Inj | outs (IN, EN) ⁽²⁾ |) | | <u></u> | | | | <u> </u> | |
| Input logic high | V _{IH} | | | Full | | 1.05 | | 5.5 | V |
| Input logic low | V _{IL} | | | Full | | | | 0.65 | V |
| Input leakage current | I _{IH} , I _{IL} | V _{IN} = 1.8 V or GND | | 25°C Full | 3.6 V | -920 -920 | | 920 920 | nA |

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

⁽²⁾ All unused digital inputs of the device must be held at V₊ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



ELECTRICAL CHARACTERISTICS FOR 3.3-V SUPPLY⁽¹⁾ (continued)

 $V_{+} = 3 \text{ V to } 3.6 \text{ V}, T_{A} = -40 ^{\circ}\text{C} \text{ to } 85 ^{\circ}\text{C} \text{ (unless otherwise noted)}$

| PARAMETER | SYMBOL | TEST CO | NDITIONS | TA | V ₊ | MIN | TYP | MAX | UNIT |
|----------------------------|--|---|--|------|----------------|-----|------|-------|------|
| Dynamic | | | | | | | | | |
| Turn-on time | t _{on} | $V_{COM} = V_+,$ | $C_L = 35 \text{ pF},$ | 25°C | 3.3 V | | 199 | 313 | ns |
| | OIV | $R_L = 300 \Omega$ | See Figure 19 | Full | 3 V to 3.6 V | | | 370 | |
| Turn-off time | t _{OFF} | $V_{COM} = V_+,$ | $C_L = 35 \text{ pF},$ | 25°C | 3.3 V | | 182 | 289.9 | ns |
| | *OFF | $R_L = 300 \Omega$, | See Figure 19 | Full | 3 V to 3.6 V | | | 350 | |
| Break-before- make time | t _{BBM} | $V_{NC} = V_{NO} = V_{+}/2$ $R_{L} = 300 \Omega,$ | $C_L = 35 \text{ pF},$ See Figure 20 | 25°C | 3.3 V | 1 | 7.1 | | ns |
| Charge injection | $Q_{\mathbb{C}}$ | $V_{GEN} = 0,$ $R_{GEN} = 0,$ | $C_L = 1 \text{ nF},$ See Figure 24 | 25°C | 3.3 V | | 120 | | рС |
| NC, NO OFF capacitance | C _{NC(OFF)} , C _{NO(OFF)} | V_{NC} or $V_{NO} = V_{+}$ or $V_{+} - 5.5 V$, Switch OFF, | See Figure 18 | 25°C | 3.3 V | | 50 | | pF |
| NC, NO ON capacitance | C _{NC(ON)} , C _{NO(ON)} | V_{NC} or $V_{NO} = V_{+}$ or GND, Switch OFF, | See Figure 18 | 25°C | 3.3 V | | 180 | | pF |
| COM ON capacitance | C _{COM(ON)} | V _{COM} = V ₊ or GND, Switch ON, | See Figure 18 | 25°C | 3.3 V | | 180 | | pF |
| Digital input capacitance | C_{l} | $V_I = V_+ \text{ or GND}$ | See Figure 18 | 25°C | 3.3 V | | 3 | | pF |
| Bandwidth | BW | $R_L = 50 \Omega$, | Switch ON, See Figure 20 | 25°C | 3.3 V | | 32 | | MHz |
| | | $R_L = 50 \Omega$, Switch | f = 100 kHz, | | | | -70 | | |
| OFF isolation | O _{ISO} | OFF, | f = 1 MHz, | 25°C | 3.3 V | | -50 | | dB |
| | | See Figure 22 | f = 5 MHz, | | | | -35 | | |
| | | $R_L = 50 \Omega$, Switch | f = 100 kHz, | | | | -70 | | |
| Crosstalk | X _{TALK} | ΟN, | f = 1 MHz, | 25°C | 3.3 V | | -50 | | dB |
| | | See Figure 23 | f = 5 MHz, | | | | -35 | | |
| Total harmonic distortion | THD | $R_L = 600 \Omega,$ $C_L = 50 pF,$ | f = 20 Hz to 20 kHz, See Figure 25 | 25°C | 3.3 V | | 0.01 | | % |
| Supply | | | | | 1. | | | | |
| Positive supply current | I ₊ | V _I = 1.8 V or GND | | Full | 3.6 V | | 6 | 13 | μΑ |

ELECTRICAL CHARACTERISTICS FOR 5-V SUPPLY⁽¹⁾

 $V_{+} = 4.5 \text{ V}$ to 5.5 V, $T_{A} = -40 ^{\circ}\text{C}$ to 85 $^{\circ}\text{C}$ (unless otherwise noted)

| PARAMETER | SYMBOL | TEST CO | NDITIONS | T _A | V ₊ | MIN | TYP | MAX | UNIT |
|-----------------------------------|--|---|------------------------------|----------------|----------------|----------------------|-------|----------------|------|
| Analog Switch | | | | | | | | | |
| Analog signal range | $V_{\rm COM}, \ V_{\rm NO}, V_{\rm NC}$ | | | | | V ₊ - 5.5 | | V ₊ | Ω |
| ON-state | | VNC or VNO = V+, | Switch ON, | 25°C | | | 0.7 | 1 | _ |
| resistance | r _{on} | $I_{COM} = -100 \text{ mA},$ | See Figure 15 | Full | 4.5 V | | | 1.36 | Ω |
| ON-state | _ | V_{NC} or $V_{NO} = 1.5 \text{ V}$, | Switch ON, | 25°C | | | 0.1 | 0.2 | |
| resistance match between channels | Δr_{on} | $I_{COM} = -100 \text{ mA},$ | See Figure 15 | Full | 4.5 V | | | 0.3 | Ω |
| ON-state | | VNC or VNO = V+, | Switch ON, | 25°C | | | 0.135 | 0.37 | |
| resistance flatness | r _{on(flat)} | $I_{COM} = -100 \text{ mA},$ | See Figure 16 | Full | 4.5 V | | | 0.51 | Ω |
| | | $V_{NC} = 4.5, V_{+} - 5.5 V$ | | 25°C | | –50 50 | | | |
| NC, NO OFF leakage current | I _{NC(OFF)} , I _{NO(OFF)} | $\begin{split} &V_{\text{COM}} = V_+ - 5.5 \text{ V}, \\ &4.5, \\ &V_{\text{NO}} = \text{Open,} \\ &\text{or} \\ &V_{\text{NO}} = 4.5, V_+ - 5.5 \text{ V} \\ &V_{\text{COM}} = V_+ - 5.5 \text{ V}, \\ &4.5, \\ &V_{\text{NC}} = \text{Open,} \end{split}$ | Switch OFF, See Figure 16 | Full | 5.5 V | -375 | | 375 | nA |
| COM | | V_{NC} and V_{NO} = Open, | Switch ON. | 25°C | | -50 | | 50 | |
| ON leakage current | I _{COM(ON)} | $V_{COM} = V_{+}, V_{+} - 5.5 \text{ V},$ | See Figure 17 | Full | 5.5 V | -375 | | 375 | nA |
| Digital Control Inp | uts (IN, EN) ⁽²⁾ | | | | | | | | |
| Input logic high | V _{IH} | | | Full | | 1.05 | | 5.5 | V |
| Input logic low | V_{IL} | | | Full | | | | 0.65 | V |
| Input leakage | las la | V _{IN} = 1.8 V or 0 | | 25°C | 5.5 V | -1.5 | | 1.5 | μA |
| current | I _{IH} , I _{IL} | VIN - 1.0 V 01 0 | | Full | 3.3 V | -1.5 | | 1.5 | μΛ |

 ⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
 (2) All unused digital inputs of the device must be held at V₊ or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



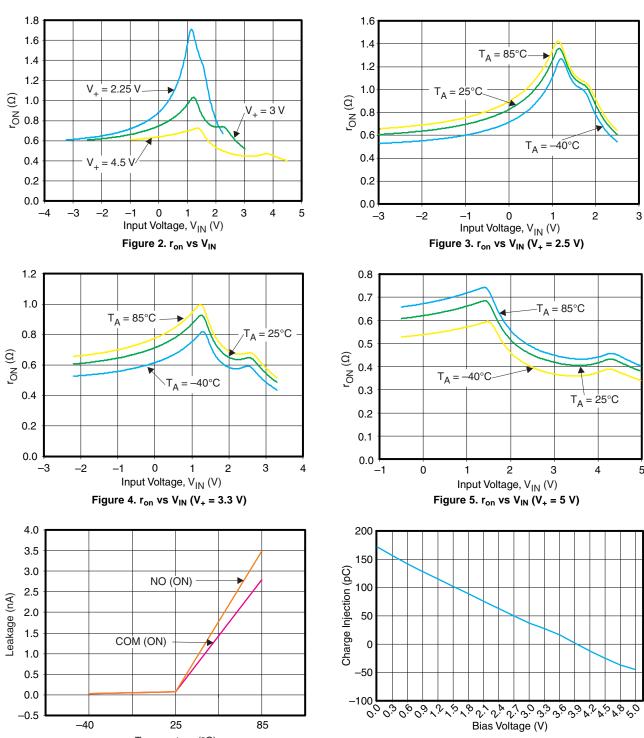
ELECTRICAL CHARACTERISTICS FOR 5-V SUPPLY⁽¹⁾ (continued)

 $V_{+} = 4.5 \text{ V}$ to 5.5 V, $T_{A} = -40^{\circ}\text{C}$ to 85°C (unless otherwise noted)

| PARAMETER | SYMBOL | TEST CO | NDITIONS | TA | V ₊ | MIN | TYP | MAX | UNIT |
|----------------------------|--|---|--|------|-------------------|-----|-----------------|-----|----------|
| Dynamic | | | | | | | | | |
| | | \/ -\/ | $C_L = 35 \text{ pF},$ | 25°C | 5 V | | 230 | 374 | |
| Turn-on time | t _{ON} | $V_{COM} = V_+,$ $R_L = 300 \Omega,$ | See Figure 19 | Full | 4.5 V to 5.5 V | | | 470 | ns |
| | | \\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\ | C _L = 35 pF, | 25°C | 5 V | | 206 | 325 | |
| Turn-off time | t _{OFF} | $V_{COM} = V_+,$ $R_L = 300 \Omega,$ | See Figure 19 | Full | 4.5 V to 5.5 V | | | 380 | ns |
| Break-before- make time | t _{BBM} | $V_{NC} = V_{NO} = V_{+}/2$ $R_{L} = 300 \Omega$, | C _L = 35 pF, See Figure 20 | 25°C | 3.3 V | 1 | 3 | | ns |
| Charge injection | Q _C | V _{GEN} = 0, R _{GEN} = 0, | C _L = 1 nF, See Figure 24 | 25°C | 5 V | | 168 | | рС |
| NC, NO OFF capacitance | C _{NC(OFF)} , C _{NO(OFF)} | V_{NC} or $V_{NO} = V_{+}$ or $V_{+} - 5.5 V$, Switch OFF, | See Figure 18 | 25°C | 5 V | | 48 | | pF |
| NC, NO ON capacitance | C _{NC(ON)} , C _{NO(ON)} | V_{NC} or $V_{NO} = V_{+}$ or $V_{+} - 5.5 V$, Switch ON, | See Figure 18 | 25°C | 5 V | | 176 | | pF |
| COM ON capacitance | C _{COM(ON)} | V _{COM} = V ₊ or GND, Switch ON, | See Figure 18 | 25°C | 5 V | | 176 | | pF |
| Digital input capacitance | C _I | $V_I = V_+ \text{ or GND}$ | See Figure 18 | 25°C | 5 V | | 3 | | pF |
| Bandwidth | BW | $R_L = 50 \Omega$, | Switch ON, See Figure 20 | 25°C | 5 V | | 32 | | MHz |
| | | $R_L = 50 \Omega$, Switch | f = 100 kHz | | | | -70 | | |
| OFF isolation | O _{ISO} | OFF, | f = 1 MHz | 25°C | 5 V | | -50 | | dB |
| | | See Figure 22 | f = 5 MHz | | | | -35 | | <u> </u> |
| | | D 50 O Outub ON | f = 100 kHz | | | | -70 | | l |
| Crosstalk | X _{TALK} | $R_L = 50 \Omega$, Switch ON, See Figure 23 | f = 1 MHz | 25°C | 5 V | | -5 0 | | dB |
| | | 3 | f = 5 MHz | | | | -35 | | <u></u> |
| Total harmonic distortion | THD | $R_L = 600 \Omega,$ $C_L = 50 pF,$ | f = 20 Hz to 20 kHz, See Figure 25 | 25°C | 5 V | | 0.01 | | % |
| Supply | | | | | | | | | |
| Positive supply current | I ₊ | V _I = 1.8 V or GND | | Full | 5.5 V | | 7 | 14 | μΑ |



TYPICAL PERFORMANCE



Temperature (°C) Figure 6. Leakage Current vs Temperature

25

85

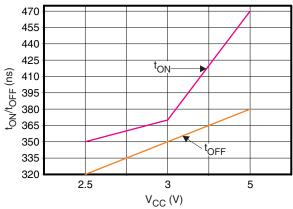
Figure 7. Charge Injection (Q_C) vs $V_{COM}(V_+ = 5 \text{ V})$

-40

-0.5



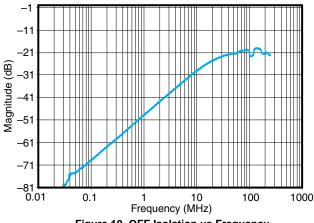




(ap) -4 -5 -5 -6 -6 -7 -7 -7 -10 -11 -12 -13 0.01 0.1 1 10 100 1000 Frequency (MHz)

Figure 8. t_{ON} and t_{OFF} vs Supply Voltage

Figure 9. Bandwidth $(V_+ = 2.5 \text{ V})$



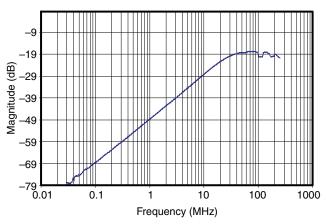
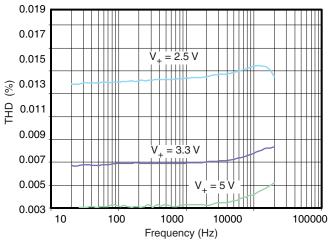


Figure 10. OFF Isolation vs Frequency

Figure 11. Crosstalk ($V_+ = 3.3 \text{ V}$)



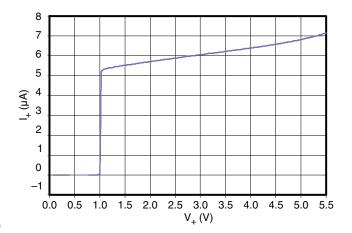


Figure 12. Total Harmonic Distortion vs Frequency

Figure 13. Power-Supply Current vs V+



TYPICAL PERFORMANCE (continued)

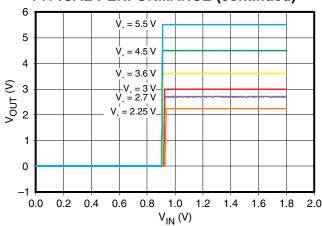


Figure 14. Control Input Thresholds



PARAMETER MEASUREMENT INFORMATION

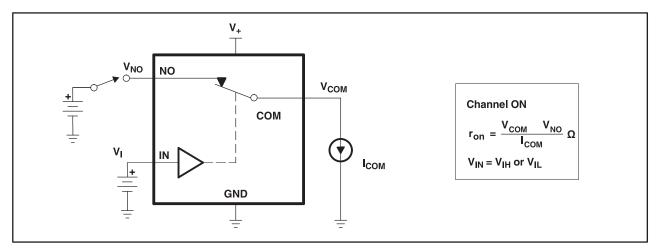


Figure 15. ON-state Resistance (r_{ON})

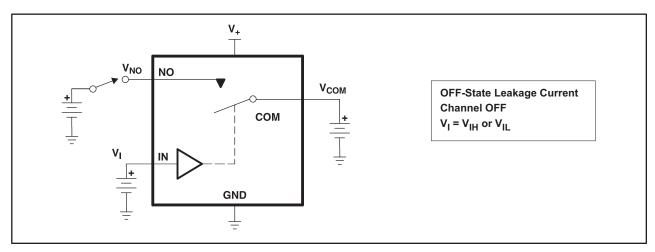


Figure 16. OFF-State Leakage Current (I_{COM(OFF)}, I_{NC(OFF)}, I_{COM(PWROFF)}, I_{NC(PWROFF)})



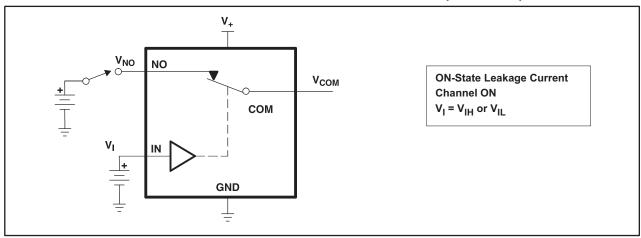


Figure 17. ON-State Leakage Current (I_{COM(ON)}, I_{NC(ON)})

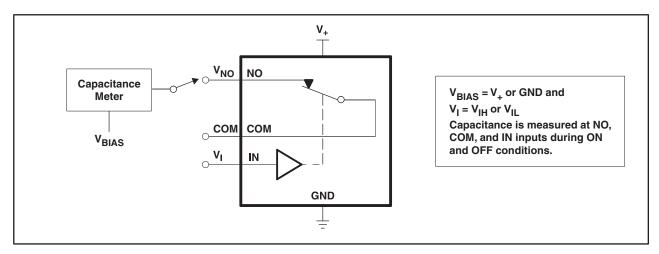


Figure 18. Capacitance (C_I, C_{COM(OFF)}, C_{COM(ON)}, C_{NC(OFF)}, C_{NC(ON)})

- A. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r < 5 \text{ ns}$, $t_f < 5 \text{ ns}$.
- B. C_L includes probe and jig capacitance.



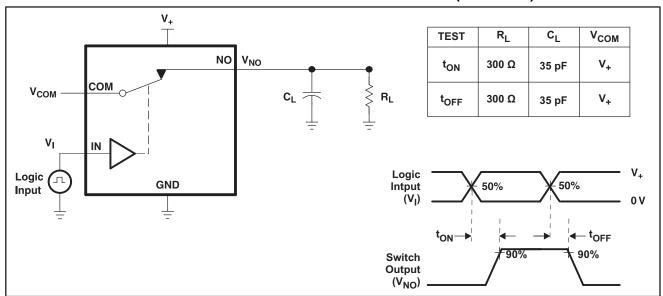


Figure 19. Turn-On (t_{ON}) and Turn-Off Time (t_{OFF})

- A. C_L includes probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \Omega$, $t_r < 5 \text{ ns}$, $t_f < 5 \text{ ns}$.

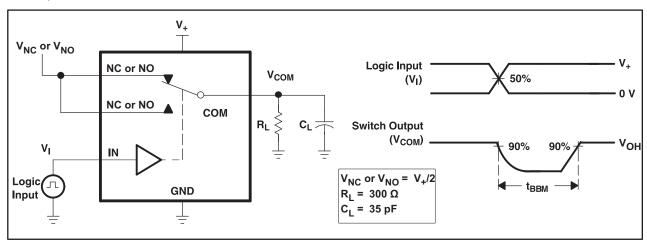


Figure 20. Break-Before-Make Time (t_{BBM})



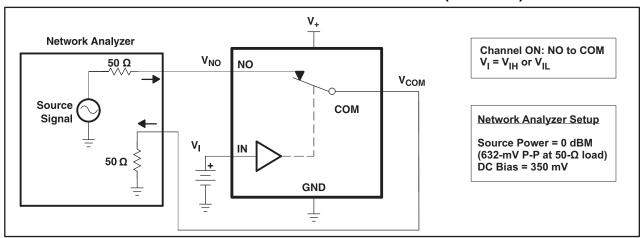


Figure 21. Bandwidth (BW)

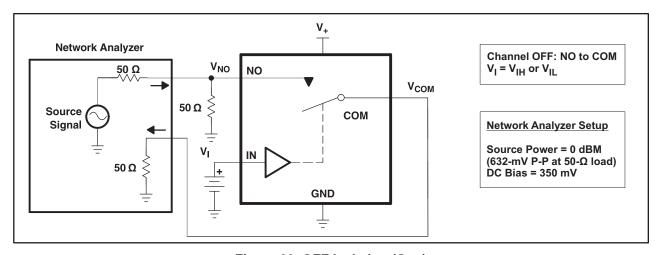


Figure 22. OFF Isolation (O_{ISO})

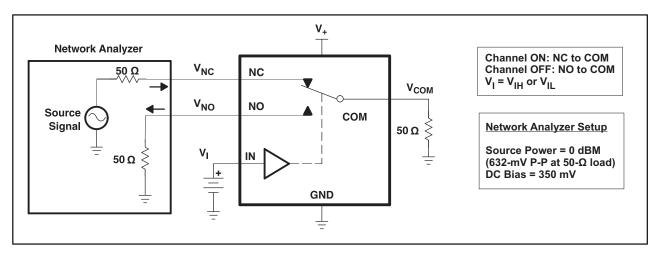


Figure 23. Crosstalk (X_{TALK})

- A. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r < 5 \text{ ns}$, $t_f < 5 \text{ ns}$.
- B. C_L includes probe and jig capacitance.



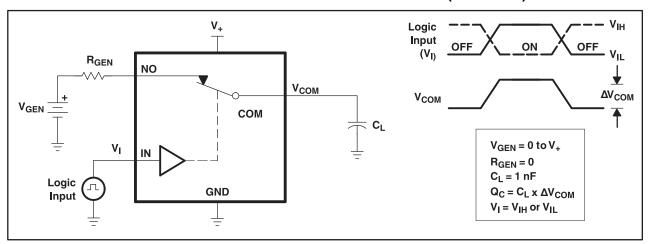


Figure 24. Charge Injection (Q_C)

A. C_L includes probe and jig capacitance.

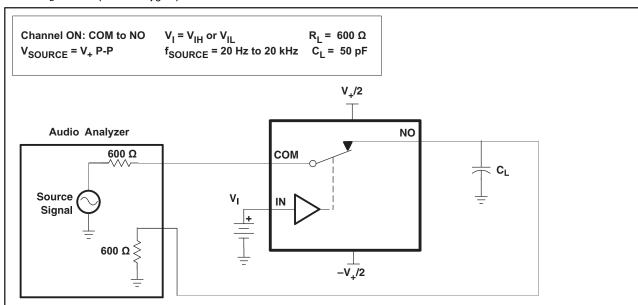


Figure 25. Total Harmonic Distortion (THD)



REVISION HISTORY

| Changes from Revision A (August 2009) to Revision B | | | | | |
|---|---|---|--|--|--|
| • | Removed QFN reference from product description. | 1 | | | |
| • | Changed Analog signal range MIN value from V ₊ – 0.5 to V ₊ – 5.5 | 7 | | | |

Product Folder Links: TS5A22366

www.ti.com 23-May-2025

PACKAGING INFORMATION

| Orderable part number | Status | Material type | Package Pins | Package qty Carrier | RoHS | Lead finish/ Ball material | MSL rating/ Peak reflow | Op temp (°C) | Part marking (6) |
|-----------------------|--------|---------------|------------------|-----------------------|------|-------------------------------|----------------------------|--------------|------------------|
| | | | | | | (4) | (5) | | |
| TS5A22366YFCR | Active | Production | DSBGA (YFC) 12 | 3000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | (3A2, 3AN) |
| TS5A22366YFCR.B | Active | Production | DSBGA (YFC) 12 | 3000 LARGE T&R | Yes | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | (3A2, 3AN) |

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE MATERIALS INFORMATION

www.ti.com 23-Mar-2024

TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TS5A22366YFCR | DSBGA | YFC | 12 | 3000 | 178.0 | 9.2 | 1.29 | 1.69 | 0.73 | 4.0 | 8.0 | Q1 |

PACKAGE MATERIALS INFORMATION

www.ti.com 23-Mar-2024

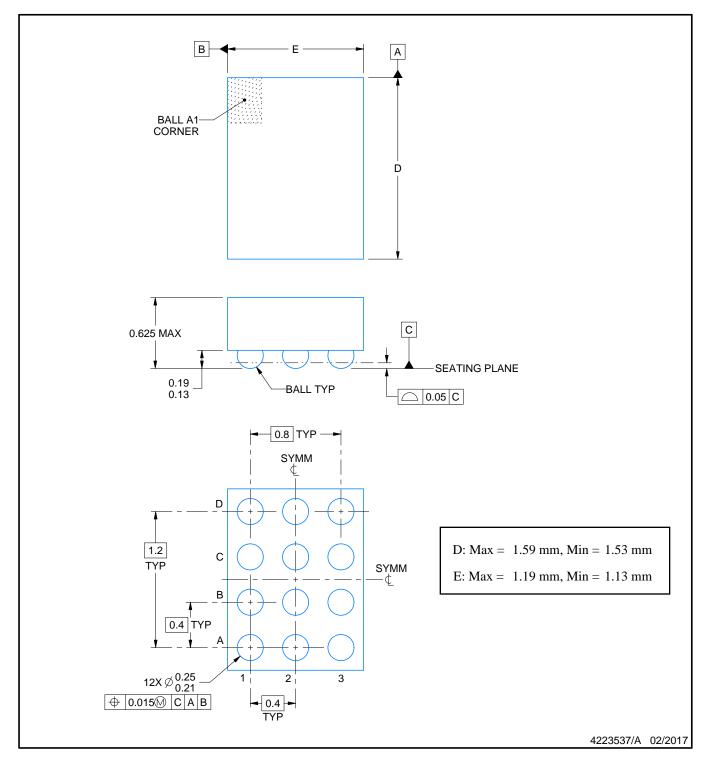


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) | |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|--|
| TS5A22366YFCR | DSBGA | YFC | 12 | 3000 | 220.0 | 220.0 | 35.0 | |



DIE SIZE BALL GRID ARRAY

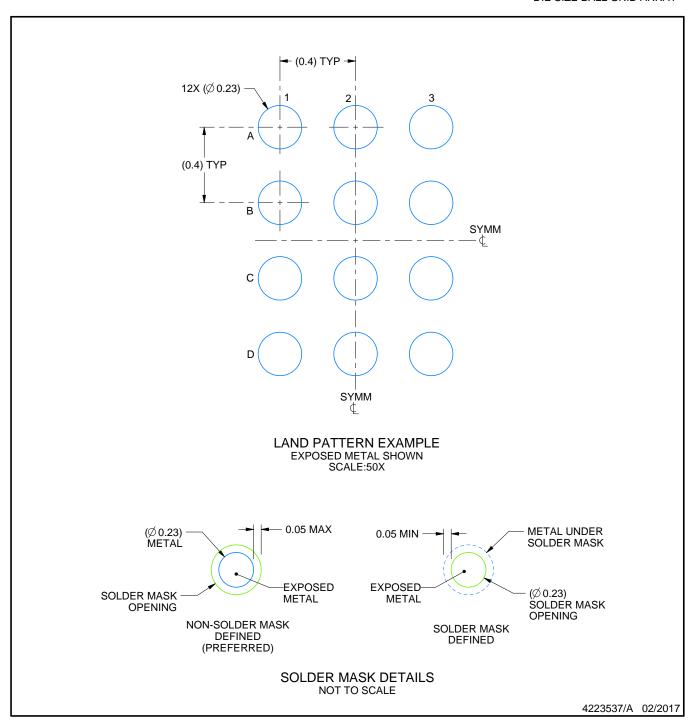


NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.



DIE SIZE BALL GRID ARRAY

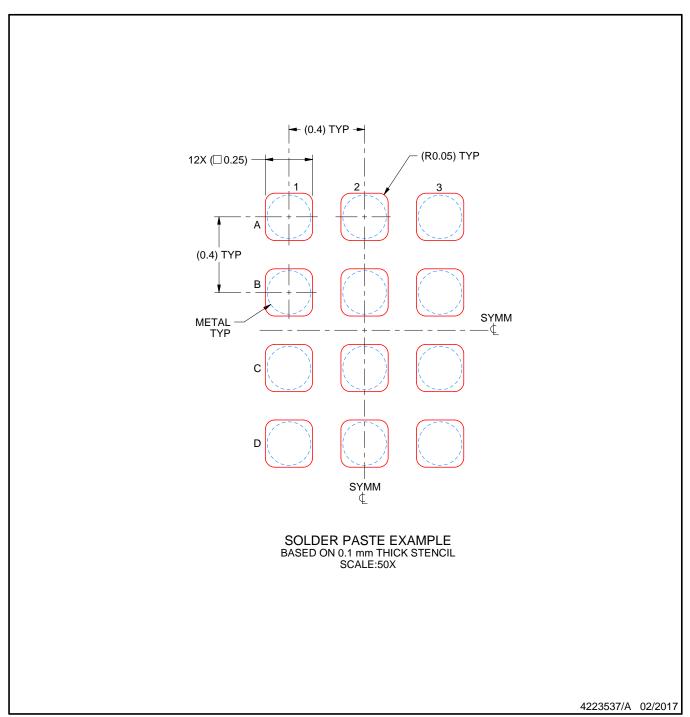


NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



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